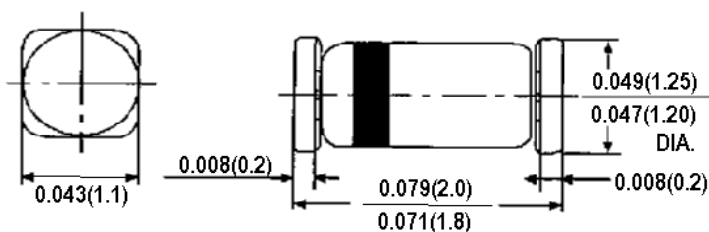


## MCL4148 Micro MELF SWITCHING Diode

**MICRO MELF (Molded Glass)**

Unit: inch (mm)



### Absolute Maximum Ratings

	Symbol	Value	UNIT
Reverse Voltage	$V_R$	75	V
Peak Reverse Voltage	$V_{RM}$	100	V
Rectifier Current (Average) Half Wave Rectification w/Resist Load at $T_{amb}=25\text{degC}$ and $F>/ 50\text{Hz}$	$I_O$	150	mA
Surge Forward Current @ $t<1\text{s}$ and $T_j=25\text{degC}$	$I_{FSM}$	500	mA
Power Dissipation at $T_{amb}= 25\text{degC}$	$P_{tot}$	500	mW
Junction Temperature	$T_j$	175	$^{\circ}\text{C}$
Storage Temperature Range	$T_s$	-65 to +175	$^{\circ}\text{C}$

### Characteristics at $T_j=25^{\circ}\text{C}$

	Symbol	Min	Max	Unit
Forward Voltage at $I_F = 10\text{ mA}$	$V_F$	-	1	V
Leakage Current at $V_R = 20\text{V}$	$I_R$	-	25	nA
at $V_R = 75\text{V}$	$I_R$	-	5	$\mu\text{A}$
at $V_R = 20\text{V}$ , $T_j = 150^{\circ}\text{C}$	$I_R$	-	50	$\mu\text{A}$
Reverse Breakdown Voltage tested with 100 $\mu\text{s}$ Pulses	$V_{(BR)R}$	100	-	V
Capacitance at $V_F=V_R= 0$	$C_{tot}$	-	4	pF
Voltage Rise when Switching On Tested with 50mA Forward Pulses $T_p=0.1\mu\text{s}$ , RiseTime<30ns, fp=5~100kHz	$V_{fr}$	-	2.5	V
Reverse Recovery Time From $I_F=-I_R=10\text{mA}$ to $I_{RR}=-1\text{mA}$ $V_R=6\text{V}$ $R_L=100\text{ ohms}$	$t_{rr}$	-	4	ns
Thermal Resistance Function to Ambient Air	$R_{thA}$	-	0.35	K/mW
Rectification Efficiency at $f=100\text{MHZ}$ , $V_{RF}= 2\text{V}$	$\eta_v$	0.45	-	-